



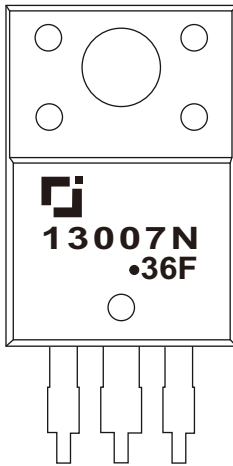
# TO-220F Plastic-Encapsulate Transistor

## 3DD13007N36F TRANSISTOR (NPN)

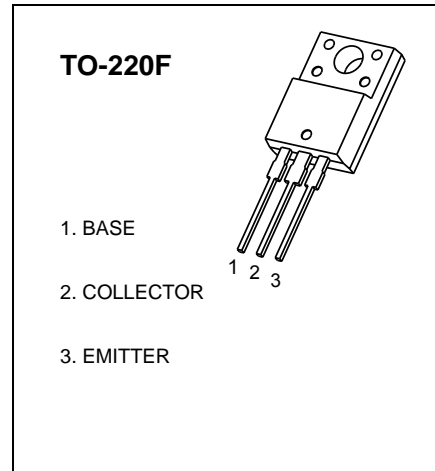
### FEATURES

- Power switching applications

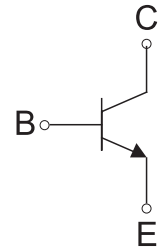
### MARKING



13007N=Device code  
 Solid dot=Green moldinn compound device,  
 if none,the normal device  
 36F=Code



### Equivalent Circuit



### MAXIMUM RATINGS (T<sub>a</sub>=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	700	V
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V
V <sub>EBO</sub>	Emitter-Base Voltage	9	V
I <sub>C</sub>	Collector Current -Continuous	8	A
P <sub>C</sub>	Collector Power Dissipation	2	W
T <sub>J</sub> , T <sub>stg</sub>	Operation Junction and Storage Temperature Range	-55~150	°C

**ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Typ	Ma	
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 1mA, I <sub>E</sub> =0	700			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =0	400			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =1mA, I <sub>C</sub> =0	9			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =700V, I <sub>E</sub> =0			100	μ A
Collector cut-off current	I <sub>CEO</sub>	V <sub>CE</sub> =400V, I <sub>B</sub> =0			100	μ A
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =9V, I <sub>C</sub> =0			100	μ A
DC current gain	h <sub>FE(1)</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =2A	10		40	
	h <sub>FE(2)</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =8A	5			
Collector-emitter saturation voltage	V <sub>CE(sat)1</sub>	I <sub>C</sub> =2A, I <sub>B</sub> =0.4A			1	V
	V <sub>CE(sat)2</sub>	I <sub>C</sub> =5A, I <sub>B</sub> =1A			2	V
	V <sub>CE(sat)3</sub>	I <sub>C</sub> =8A, I <sub>B</sub> =2A			3	V
Base-emitter saturation voltage	V <sub>BE(sat)1</sub>	I <sub>C</sub> =2A, I <sub>B</sub> =0.4A			1.2	V
	V <sub>BE(sat)2</sub>	I <sub>C</sub> =5A, I <sub>B</sub> =1A			1.6	V
Storage time	t <sub>S</sub>	I <sub>C</sub> =500mA (UI9600)	3		6	μ s
Fall time	t <sub>f</sub>	I <sub>C</sub> =500mA (UI9600)			0.5	μ s
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =0.5A, f=1MHz	4			MHz

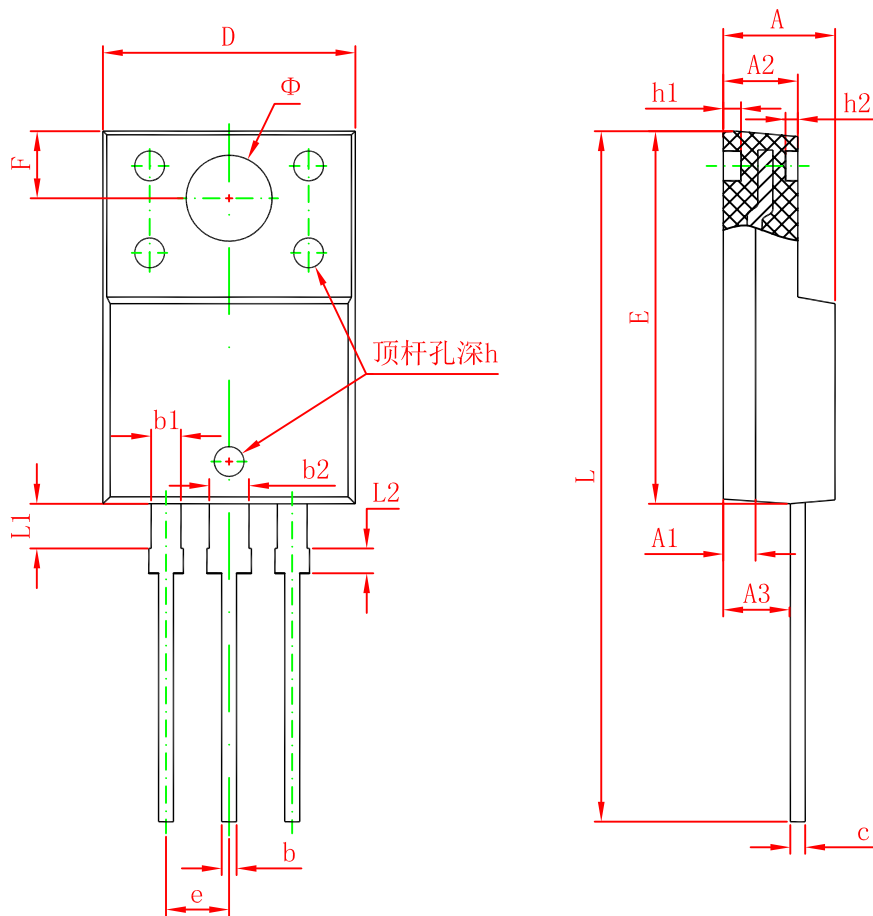
**CLASSIFICATION OF h<sub>FE(1)</sub>**

Range	10-15	15-20	20-25	25-30	30-35	35-40

**CLASSIFICATION OF t<sub>S</sub>**

Rank	A	B	C
Range	3-4( μ s )	4-5( μ s )	5-6 ( μ s )

# TO-220F Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.300	4.700	0.169	0.185
A1	1.300 REF.		0.051 REF.	
A2	2.800	3.200	0.110	0.126
A3	2.500	2.900	0.098	0.114
b	0.500	0.750	0.020	0.030
b1	1.100	1.350	0.043	0.053
b2	1.500	1.750	0.059	0.069
c	0.500	0.750	0.020	0.030
D	9.960	10.360	0.392	0.408
E	14.800	15.200	0.583	0.598
e	2.540 TYP.		0.100 TYP.	
F	2.700 REF.		0.106 REF.	
Φ	3.500 REF.		0.138 REF.	
h	0.000	0.300	0.000	0.012
h1	0.800 REF.		0.031 REF.	
h2	0.500 REF.		0.020 REF.	
L	28.000	28.400	1.102	1.118
L1	1.700	1.900	0.067	0.075
L2	0.900	1.100	0.035	0.043